Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-410-7232

nclosure Material:	
Metal	
Overall Length:	
I.390 inches	
Mounting Facility Quantity:	
Joint Electronic Device Engineering Council/jedec/case Outline Designa	tion:
Do-5	
Electrode Internally-electrically Connected To Case:	
Cathode	
Mounting Method:	
Threaded stud	
Features Provided:	
Hermetically sealed case	
Overall Width Across Flats:	
0.687 inches	
Thread Size:	
0.250 inches	
Semiconductor Material:	
Silicon	
/oltage Rating In Volts Per Characteristic:	
6.2 regulator voltage	
/oltage Tolerance In Percent:	
5.0/+5.0	
Current Rating Per Characteristic:	
7.65 amperes source cutoff current horsepower metric	
Power Rating Per Characteristic:	
50.0 watts small-signal input power, common-collector preset	
Maximum Operating Tempurature Per Measurement Point:	
175.0 degrees celsius junction	
Thread Series Designator:	
Jnf	
Terminal Type And Quantity:	
I tab, solder lug and 1 threaded stud	
Shelf Life:	
N/a	
Jnit Of Measure:	
-	
Demilitarization:	
Yes - demil/mli	
-iig:	
A110a0	